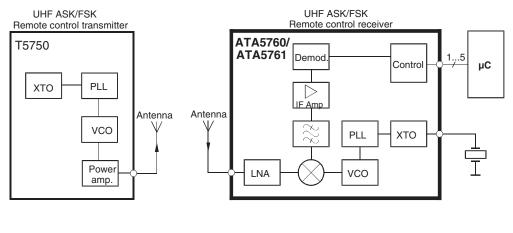
Features

- Two Different IF Receiving Bandwidth Versions Are Available (B_{IF} = 300 kHz or 600 kHz)
- Frequency Receiving Range of $f_0 = 868$ MHz to 870 MHz or $f_0 = 902$ MHz to 928 MHz
- 30 dB Image Rejection
- Receiving Bandwidth B_{IF} = 600 kHz for Low Cost 90-ppm Crystals and B_{IF} = 300 kHz for 55 ppm Crystals
- Fully Integrated LC-VCO and PLL Loop Filter
- Very High Sensitivity with Power Matched LNA
- High System IIP3 (-16 dBm), System 1-dB Compression Point (-25 dBm)
- High Large-signal Capability at GSM Band
- (Blocking –30 dBm at +20 MHz, IIP3 = –12 dBm at +20 MHz)
- 5V to 20V Automotive Compatible Data Interface
- Data Clock Available for Manchester- and Bi-phase-coded Signals
- Programmable Digital Noise Suppression
- Low Power Consumption Due to Configurable Polling
- Temperature Range –40°C to +105°C
- ESD Protection 2 kV HBM, All Pins
- Communication to Microcontroller Possible Via a Single Bi-directional Data Line
- Low-cost Solution Due to High Integration Level with Minimum External Circuitry Requirements

1. Description

The ATA5760/ATA5761 is a multi-chip PLL receiver device supplied in an SO20 package. It has been especially developed for the demands of RF low-cost data transmission systems with data rates from 1 kBaud to 10 kBaud in Manchester or Bi-phase code. The receiver is well suited to operate with the Atmel's PLL RF transmitter T5750. Its main applications are in the areas of telemetering, security technology and keyless-entry systems. It can be used in the frequency receiving range of $f_0 = 868$ MHz to 870 MHz or $f_0 = 902$ MHz to 928 MHz for ASK or FSK data transmission. All the statements made below refer to 868.3 MHz and 915.0 MHz applications.







UHF ASK/FSK Receiver

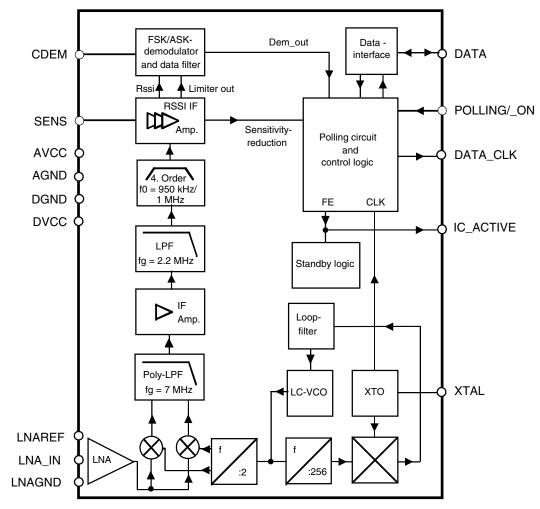
ATA5760 ATA5761

4896D-RKE-08/08





Figure 1-2. Block Diagram



2. Pin Configuration

Figure 2-1. Pinning SO20

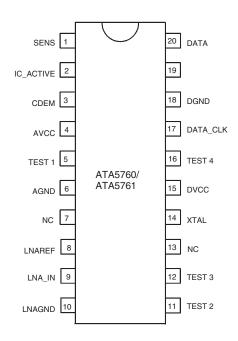


Table 2-1.	Pin Description
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	Fill Description	
Pin	Symbol	Function
1	SENS	Sensitivity-control resistor
2	IC_ACTIVE	IC condition indicator: Low = sleep mode, High = active mode
3	CDEM	Lower cut-off frequency data filter
4	AVCC	Analog power supply
5	TEST 1	Test pin, during operation at GND
6	AGND	Analog ground
7	NC	Not connected, connect to GND
8	LNAREF	High-frequency reference node LNA and mixer
9	LNA_IN	RF input
10	LNAGND	DC ground LNA and mixer
11	TEST 2	Do not connect during operating
12	TEST 3	Test pin, during operation at GND
13	NC	Not connected, connect to GND
14	XTAL	Crystal oscillator XTAL connection
15	DVCC	Digital power supply
16	TEST 4	Test pin, during operation at DVCC
17	DATA_CLK	Bit clock of data stream
18	DGND	Digital ground
19	POLLING/_ON	Selects polling or receiving mode; Low: receiving mode, High: polling mode
20	DATA	Data output/configuration input





3. RF Front End

The RF front end of the receiver is a low-IF heterodyne configuration that converts the input signal into an about 1 MHz IF signal with an image rejection of typical 30 dB. According to Figure 2-1 on page 3 the front end consists of an LNA (Low Noise Amplifier), LO (Local Oscillator), I/Q mixer, polyphase lowpass filter and an IF amplifier.

The PLL generates the carrier frequency for the mixer via a full integrated synthesizer with integrated low noise LC-VCO (Voltage Controlled Oscillator) and PLL-loop filter. The XTO (crystal oscillator) generates the reference frequency f_{XTO} . The integrated LC-VCO generates two times the mixer drive frequency f_{VCO} . The I/Q signals for the mixer are generated with a divide by two circuit ($f_{LO} = f_{VCO}/2$). f_{VCO} is divided by a factor of 256 and feeds into a phase frequency detector and compared with f_{XTO} . The output of the phase frequency detector is fed into an integrated loop filter and thereby generates the control voltage for the VCO. If f_{LO} is determined, f_{XTO} can be calculated using the following formula:

 $f_{XTO} = f_{LO}/128$

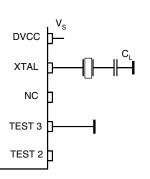
The XTO is a one-pin oscillator that operates at the series resonance of the quartz crystal with high current but low voltage signal, so that there is only a small voltage at the crystal oscillator frequency at pin XTAL. According to Figure 3-1, the crystal should be connected to GND with a series capacitor C_L . The value of that capacitor is recommended by the crystal supplier. Due to a somewhat inductive impedance at steady state oscillation and some PCB parasitics a lower value of C_L is normally necessary.

The value of C_L should be optimized for the individual board layout to achieve the exact value of f_{XTO} (the best way is to use a crystal with known load resonance frequency to find the right value for this capacitor) and hereby of f_{LO} . When designing the system in terms of receiving bandwidth and local oscillator accuracy, the accuracy of the crystal and the XTO must be considered.

If a crystal with ± 30 ppm adjustment tolerance at 25°C, ± 50 ppm over temperature -40°C to ± 105 °C, ± 10 ppm of total aging and a CM (motional capacitance) of 7 fF is used, an additional XTO pulling of ± 30 ppm has to be added.

The resulting total LO tolerance of ± 120 ppm agrees with the receiving bandwidth specification of the 600 kHz version of ATA5760/ATA5761 if the T5750 has also a total LO tolerance of ± 120 ppm.

For the ATA5760N3 crystals with \pm 55 ppm total tolerance are needed for receiver and transmitter to cope with the reduced IF-bandwidth.





The nominal frequency f_{LO} is determined by the RF input frequency f_{RF} and the IF frequency f_{IF} using the following formula (low side injection):

 $f_{LO} = f_{RF} - f_{IF}$

To determine f_{LO} , the construction of the IF filter must be considered at this point. The nominal IF frequency is $f_{IF} = 950$ kHz. To achieve a good accuracy of the filter corner frequencies, the filter is tuned by the crystal frequency f_{XTO} . This means that there is a fixed relation between f_{IF} and f_{LO} .

 $f_{IF} = f_{LO}/915$ for $B_{IF} = 600$ kHz

 $f_{IF} = f_{LO}/878$ for $B_{IF} = 300$ kHz

The relation is designed to achieve the nominal IF frequency of

 $f_{\rm IF}$ = 950 kHz for the 868.3 MHz and $B_{\rm IF}$ = 600 kHz version, $f_{\rm IF}$ = 989 kHz for the 868.3 MHz and $B_{\rm IF}$ = 300 kHz version and for the 915 MHz version an IF frequency of $f_{\rm IF}$ = 1.0 MHz results.

The RF input either from an antenna or from an RF generator must be transformed to the RF input pin LNA_IN. The input impedance of that pin is provided in the electrical parameters. The parasitic board inductances and capacitances influence the input matching. The RF receiver ATA5760/ATA5761 exhibits its highest sensitivity if the LNA is power matched. This makes the matching to an SAW filter as well as to 50Ω or an antenna easier.

Figure 14-1 on page 30 shows a typical input matching network for f_{RF} = 868.3 MHz to 50 Ω Figure 14-2 on page 30 illustrates an according input matching for 868.3 MHz to an SAW. The input matching network shown in Figure 14-1 on page 30 is the reference network for the parameters given in the electrical characteristics.





4. Analog Signal Processing

4.1 IF Filter

The signals coming from the RF front-end are filtered by the fully integrated 4th-order IF filter. The IF center frequency is

 $f_{\rm IF}$ = 950 kHz for the 868.3 MHz and $B_{\rm IF}$ = 600 kHz version, $f_{\rm IF}$ = 989 kHz for the 868.3 MHz and $B_{\rm IF}$ = 300 kHz version and $f_{\rm IF}$ = 1 MHz for the 915 MHz version.

The nominal bandwidth is $\rm B_{IF}$ = 600 kHz for ATA5760/ATA5761 and $\rm B_{IF}$ = 300 kHz for ATA5760N3.

4.2 Limiting RSSI Amplifier

The subsequent RSSI amplifier enhances the output signal of the IF amplifier before it is fed into the demodulator. The dynamic range of this amplifier is $\Delta R_{RSSI} = 60 \text{ dB}$. If the RSSI amplifier is operated within its linear range, the best S/N ratio is maintained in ASK mode. If the dynamic range is exceeded by the transmitter signal, the S/N ratio is defined by the ratio of the maximum RSSI output voltage and the RSSI output voltage due to a disturber. The dynamic range of the RSSI amplifier is exceeded if the RF input signal is about 60 dB higher compared to the RF input signal at full sensitivity.

In FSK mode the S/N ratio is not affected by the dynamic range of the RSSI amplifier, because only the hard limited signal from a high gain limiting amplifier is used by the demodulator.

The output voltage of the RSSI amplifier is internally compared to a threshold voltage V_{Th_red} . V_{Th_red} is determined by the value of the external resistor R_{Sens} . R_{Sens} is connected between pin SENS and GND or V_S . The output of the comparator is fed into the digital control logic. By this means it is possible to operate the receiver at a lower sensitivity.

If R_{Sens} is connected to GND, the receiver switches to full sensitivity. It is also possible to connect the pin SENS directly to GND to get the maximum sensitivity.

If R_{Sens} is connected to V_S , the receiver operates at a lower sensitivity. The reduced sensitivity is defined by the value of R_{Sens} , the maximum sensitivity by the signal-to-noise ratio of the LNA input. The reduced sensitivity depends on the signal strength at the output of the RSSI amplifier.

Since different RF input networks may exhibit slightly different values for the LNA gain, the sensitivity values given in the electrical characteristics refer to a specific input matching. This matching is illustrated in Figure 14-1 on page 30 and exhibits the best possible sensitivity and at the same time power matching at RF_IN.

 R_{Sens} can be connected to V_S or GND via a microcontroller. The receiver can be switched from full sensitivity to reduced sensitivity or vice versa at any time. In polling mode, the receiver will not wake up if the RF input signal does not exceed the selected sensitivity. If the receiver is already active, the data stream at pin DATA will disappear when the input signal is lower than defined by the reduced sensitivity. Instead of the data stream, the pattern according to Figure 4-1 is issued at pin DATA to indicate that the receiver is still active (see Figure 13-2 on page 28).

Figure 4-1. Steady L State Limited DATA Output Pattern

ATA5760/ATA5761

4.3 FSK/ASK Demodulator and Data Filter

The signal coming from the RSSI amplifier is converted into the raw data signal by the ASK/FSK demodulator. The operating mode of the demodulator is set via the bit ASK/_FSK in the OPMODE register. Logic L sets the demodulator to FSK, applying H to ASK mode.

In ASK mode an automatic threshold control circuit (ATC) is employed to set the detection reference voltage to a value where a good signal to noise ratio is achieved. This circuit also implies the effective suppression of any kind of in-band noise signals or competing transmitters. If the S/N (ratio to suppress in-band noise signals) exceeds about 10 dB the data signal can be detected properly, but better values are found for many modulation schemes of the competing transmitter.

The FSK demodulator is intended to be used for an FSK deviation of 10 kHz $\leq \Delta f \leq 100$ kHz. In FSK mode the data signal can be detected if the S/N (ratio to suppress in-band noise signals) exceeds about 2 dB. This value is valid for all modulation schemes of a disturber signal.

The output signal of the demodulator is filtered by the data filter before it is fed into the digital signal processing circuit. The data filter improves the S/N ratio as its passband can be adopted to the characteristics of the data signal. The data filter consists of a 1st-order high pass and a 2nd-order lowpass filter.

The highpass filter cut-off frequency is defined by an external capacitor connected to pin CDEM. The cut-off frequency of the highpass filter is defined by the following formula:

$$fcu_DF = \frac{1}{2 \times \pi \times 30 \text{ k}\Omega \times \text{CDEM}}$$

In self-polling mode, the data filter must settle very rapidly to achieve a low current consumption. Therefore, CDEM cannot be increased to very high values if self-polling is used. On the other hand CDEM must be large enough to meet the data filter requirements according to the data signal. Recommended values for CDEM are given in the electrical characteristics.

The cut-off frequency of the lowpass filter is defined by the selected baud-rate range (BR_Range). The BR_Range is defined in the OPMODE register (refer to section "Configuration of the Receiver" on page 23). The BR_Range must be set in accordance to the used baud-rate.

The ATA5760/ATA5761 is designed to operate with data coding where the DC level of the data signal is 50%. This is valid for Manchester and Bi-phase coding. If other modulation schemes are used, the DC level should always remain within the range of $V_{DC_{min}} = 33\%$ and $V_{DC_{max}} = 66\%$. The sensitivity may be reduced by up to 2 dB in that condition.

Each BR_Range is also defined by a minimum and a maximum edge-to-edge time (t_{ee_sig}). These limits are defined in the electrical characteristics. They should not be exceeded to maintain full sensitivity of the receiver.





5. Receiving Characteristics

The RF receiver ATA5760/ATA5761 can be operated with and without a SAW front-end filter. In a typical automotive application, a SAW filter is used to achieve better selectivity and large signal capability. The receiving frequency response without a SAW front-end filter is illustrated in Figure 5-1 and Figure 5-2 on page 8. This example relates to ASK mode and the 600 kHz version ATA5760N3. FSK mode exhibits a similar behavior. The plots are printed relatively to the maximum sensitivity. If a SAW filter is used, an insertion loss of about 3 dB must be considered, but the overall selectivity is much better.

When designing the system in terms of receiving bandwidth, the LO deviation must be considered as it also determines the IF center frequency. The total LO deviation is calculated, to be the sum of the deviation of the crystal and the XTO deviation of the ATA5760/ATA5761. Low-cost crystals are specified to be within ± 90 ppm over tolerance, temperature and aging. The XTO deviation of the ATA5760/ATA5761 is an additional deviation due to the XTO circuit. This deviation is specified to be ± 30 ppm worst case for a crystal with CM = 7 fF. If a crystal of ± 90 ppm is used, the total deviation is ± 120 ppm in that case. Note that the receiving bandwidth and the IF-filter bandwidth are equivalent in ASK mode but not in FSK mode.

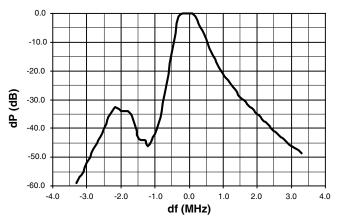
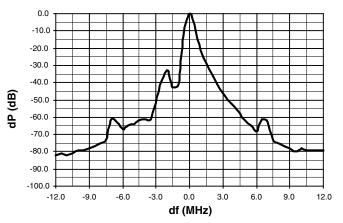


Figure 5-1. Narrow Band Receiving Frequency Response (B_{IF} = 600 kHz)

Figure 5-2. Wide Band Receiving Frequency Response (B_{IF} = 600 kHz)



8

6. Polling Circuit and Control Logic

The receiver is designed to consume less than 1 mA while being sensitive to signals from a corresponding transmitter. This is achieved via the polling circuit. This circuit enables the signal path periodically for a short time. During this time the bit-check logic verifies the presence of a valid transmitter signal. Only if a valid signal is detected, the receiver remains active and transfers the data to the connected microcontroller. If there is no valid signal present, the receiver is in sleep mode most of the time resulting in low current consumption. This condition is called polling mode. A connected microcontroller is disabled during that time.

All relevant parameters of the polling logic can be configured by the connected microcontroller. This flexibility enables the user to meet the specifications in terms of current consumption, system response time, data rate etc.

Regarding the number of connection wires to the microcontroller, the receiver is very flexible. It can be either operated by a single bi-directional line to save ports to the connected microcontroller or it can be operated by up to five uni-directional ports.

7. Basic Clock Cycle of the Digital Circuitry

The complete timing of the digital circuitry and the analog filtering is derived from one clock. This clock cycle T_{Clk} is derived from the crystal oscillator (XTO) in combination with a divide by 14 circuit. According to section "RF Front End" on page 4, the frequency of the crystal oscillator (f_{XTO}) is defined by the RF input signal (f_{RFin}) which also defines the operating frequency of the local oscillator (f_{LO}). The basic clock cycle is $T_{Clk} = 14/f_{XTO}$ giving $T_{Clk} = 2.066 \ \mu s$ for $f_{RF} = 868.3 \ MHz$ and $T_{Clk} = 1.961 \ \mu s$ for $f_{RF} = 915 \ MHz$.

T_{Clk} controls the following application-relevant parameters:

- Timing of the polling circuit including bit check
- Timing of the analog and digital signal processing
- Timing of the register programming
- Frequency of the reset marker
- IF filter center frequency (f_{IF0})

Most applications are dominated by two transmission frequencies: $f_{Transmit} = 915$ MHz is mainly used in USA, $f_{Transmit} = 868.3$ MHz in Europe. In order to ease the usage of all T_{Clk} -dependent parameters on this electrical characteristics display three conditions for each parameter.

- Application USA (f_{XTO} = 7.14063 MHz, T_{Clk} = 1.961 µs)
- Application Europe
 - ($f_{XTO} = 6.77617 \text{ MHz}, T_{Clk} = 2.066 \text{ }\mu\text{s}$) for $B_{IF} = 600 \text{ }k\text{Hz}$

(f_{XTO} = 6.77587 MHz, T_{Clk} = 2.066 \ \mu s) for B_{IF} = 300 kHz

• Other applications The electrical characteristic is given as a function of T_{Clk}.

The clock cycle of some function blocks depends on the selected baud-rate range (BR_Range) which is defined in the OPMODE register. This clock cycle T_{XClk} is defined by the following formulas for further reference:

BR_Range =	BR_Range0:	$T_{XClk} = 8 \times T_{Clk}$
	BR_Range1:	$T_{XClk} = 4 \times T_{Clk}$
	BR_Range2:	$T_{XClk} = 2 \times T_{Clk}$
	BR_Range3:	$T_{XClk} = 1 \times T_{Clk}$





8. Polling Mode

According to Figure 8-4 on page 13, the receiver stays in polling mode in a continuous cycle of three different modes. In sleep mode the signal processing circuitry is disabled for the time period T_{Sleep} while consuming low current of $I_S = I_{Soff}$. During the start-up period, $T_{Startup}$, all signal processing circuits are enabled and settled. In the following bit-check mode, the incoming data stream is analyzed bit by bit contra a valid transmitter signal. If no valid signal is present, the receiver is set back to sleep mode after the period $T_{Bit-check}$. This period varies check by check as it is a statistical process. An average value for $T_{Bit-check}$ is given in the electrical characteristics. During $T_{Startup}$ and $T_{Bit-check}$ the current consumption is $I_S = I_{Son}$. The condition of the receiver is indicated on pin IC_ACTIVE. The average current consumption in polling mode is dependent on the duty cycle of the active mode and can be calculated as:

$$_{\text{Spoll}} = \frac{I_{\text{Soff}} \times T_{\text{Sleep}} + I_{\text{Son}} \times (T_{\text{Startup}} + T_{\text{Bit-check}})}{T_{\text{Sleep}} + T_{\text{Startup}} + T_{\text{Bit-check}}}$$

During T_{Sleep} and $T_{Startup}$ the receiver is not sensitive to a transmitter signal. To guarantee the reception of a transmitted command the transmitter must start the telegram with an adequate preburst. The required length of the preburst depends on the polling parameters T_{Sleep} , $T_{Startup}$, $T_{Bit-check}$ and the start-up time of a connected microcontroller ($T_{Start_microcontroller}$). Thus, $T_{Bit-check}$ depends on the actual bit rate and the number of bits ($N_{Bit-check}$) to be tested.

The following formula indicates how to calculate the preburst length.

 $T_{Preburst} \ge T_{Sleep} + T_{Startup} + T_{Bit-check} + T_{Start_microcontroller}$

8.1 Sleep Mode

The length of period T_{Sleep} is defined by the 5-bit word Sleep of the OPMODE register, the extension factor X_{Sleep} (according to Table 11-8 on page 25), and the basic clock cycle T_{Clk} . It is calculated to be:

 $T_{Sleep} = Sleep \times X_{Sleep} \times 1024 \times T_{Clk}$

In US- and European applications, the maximum value of T_{Sleep} is about 60 ms if X_{Sleep} is set to 1. The time resolution is about 2 ms in that case. The sleep time can be extended to almost half a second by setting X_{Sleep} to 8. X_{Sleep} can be set to 8 by bit $X_{SleepStd}$ to'1'.

According to Table 11-7 on page 25, the highest register value of sleep sets the receiver into a permanent sleep condition. The receiver remains in that condition until another value for Sleep is programmed into the OPMODE register. This function is desirable where several devices share a single data line and may also be used for microcontroller polling – via pin POLLING/_ON, the receiver can be switched on and off.

Figure 8-1. Polling Mode Flow Chart

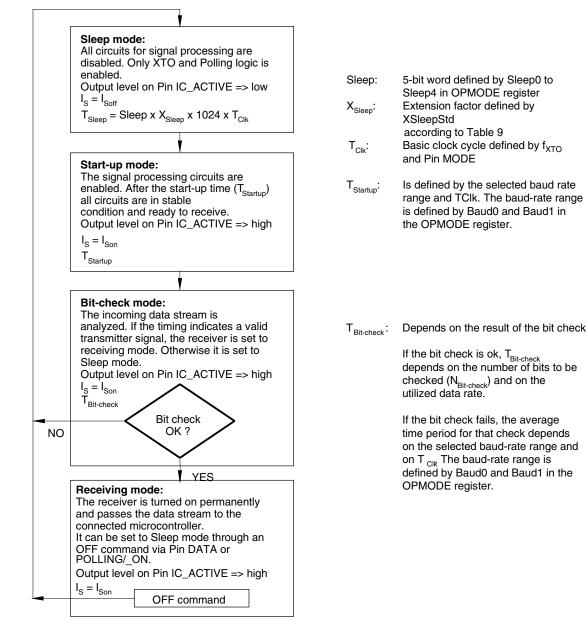
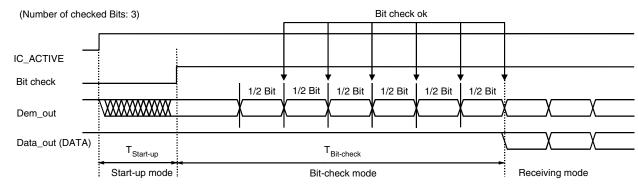


Figure 8-2. Timing Diagram for Complete Successful Bit Check







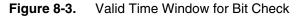
8.2 Bit-check Mode

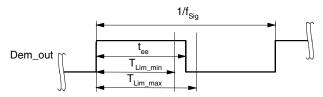
In bit-check mode the incoming data stream is examined to distinguish between a valid signal from a corresponding transmitter and signals due to noise. This is done by subsequent time frame checks where the distances between 2 signal edges are continuously compared to a programmable time window. The maximum count of this edge-to-edge tests before the receiver switches to receiving mode is also programmable.

8.3 Configuring the Bit Check

Assuming a modulation scheme that contains 2 edges per bit, two time frame checks are verifying one bit. This is valid for Manchester, Bi-phase and most other modulation schemes. The maximum count of bits to be checked can be set to 0, 3, 6 or 9 bits via the variable $N_{Bit-check}$ in the OPMODE register. This implies 0, 6, 12 and 18 edge-to-edge checks respectively. If $N_{Bit-check}$ is set to a higher value, the receiver is less likely to switch to receiving mode due to noise. In the presence of a valid transmitter signal, the bit check takes less time if $N_{Bit-check}$ is set to a lower value. In polling mode, the bit-check time is not dependent on $N_{Bit-check}$. Figure 8-2 on page 11 shows an example where 3 bits are tested successfully and the data signal is transferred to pin DATA.

According to Figure 8-3, the time window for the bit check is defined by two separate time limits. If the edge-to-edge time t_{ee} is in between the lower bit-check limit T_{Lim_min} and the upper bit-check limit T_{Lim_max} , the check will be continued. If t_{ee} is smaller than T_{Lim_min} or t_{ee} exceeds T_{Lim_max} , the bit check will be terminated and the receiver switches to sleep mode.





For best noise immunity it is recommended to use a low span between T_{Lim_min} and T_{Lim_max} . This is achieved using a fixed frequency at a 50% duty cycle for the transmitter preburst. A '11111...' or a '10101...' sequence in Manchester or Bi-phase is a good choice concerning that advice. A good compromise between receiver sensitivity and susceptibility to noise is a time window of ±30% regarding the expected edge-to-edge time t_{ee} . Using pre-burst patterns that contain various edge-to-edge time periods, the bit-check limits must be programmed according to the required span.

The bit-check limits are determined by means of the formula below.

$$\begin{split} T_{Lim_min} &= Lim_min \times \ T_{XClk} \\ T_{Lim_max} &= (Lim_max - 1) \times \ T_{XClk} \end{split}$$

Lim_min and Lim_max are defined by a 5-bit word each within the LIMIT register.

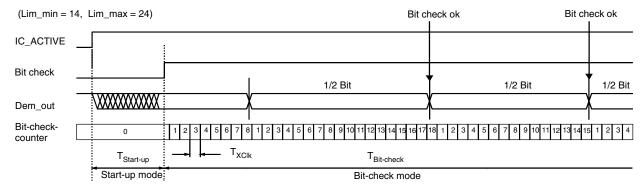
Using above formulas, Lim_min and Lim_max can be determined according to the required T_{Lim_min} , T_{Lim_max} and T_{XClk} . The time resolution defining T_{Lim_min} and T_{Lim_max} is T_{XClk} . The minimum edge-to-edge time t_{ee} ($t_{DATA_L_min}$, $t_{DATA_H_min}$) is defined according to the section "Receiving Mode" on page 14. The lower limit should be set to Lim_min ≥ 10. The maximum value of the upper limit is Lim_max = 63.

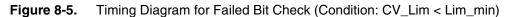
If the calculated value for Lim_min is < 19, it is recommended to check 6 or 9 bits ($N_{Bit-check}$) to prevent switching to receiving mode due to noise.

Figure 8-7 on page 15, Figure 8-8 and Figure 8-9 on page 15 illustrate the bit check for the bit-check limits Lim_min = 14 and Lim_max = 24. When the IC is enabled, the signal processing circuits are enabled during $T_{Startup}$. The output of the ASK/FSK demodulator (Dem_out) is undefined during that period. When the bit check becomes active, the bit-check counter is clocked with the cycle T_{XClk} .

Figure 8-7 on page 15 shows how the bit check proceeds if the bit-check counter value CV_Lim is within the limits defined by Lim_min and Lim_max at the occurrence of a signal edge. In Figure 8-8 on page 15 the bit check fails as the value CV_Lim is lower than the limit Lim_min. The bit check also fails if CV_Lim reaches Lim_max. This is illustrated in Figure 8-9 on page 15.







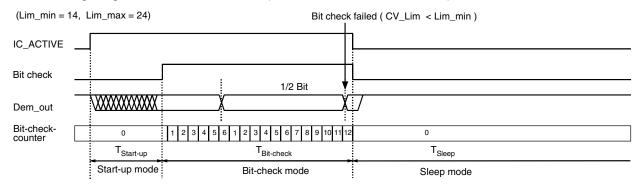
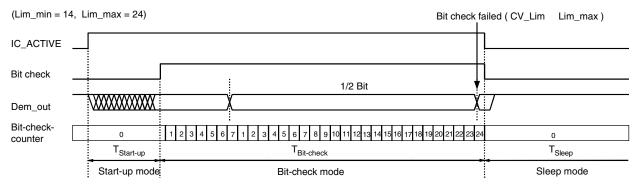






Figure 8-6. Timing Diagram for Failed Bit Check (Condition: CV_Lim ≥ Lim_max)



8.4 Duration of the Bit Check

If no transmitter signal is present during the bit check, the output of the ASK/FSK demodulator delivers random signals. The bit check is a statistical process and $T_{Bit-check}$ varies for each check. Therefore, an average value for $T_{Bit-check}$ is given in the electrical characteristics. $T_{Bit-check}$ depends on the selected baud-rate range and on T_{Clk} . A higher baud-rate range causes a lower value for $T_{Bit-check}$ resulting in a lower current consumption in polling mode.

In the presence of a valid transmitter signal, $T_{Bit-check}$ is dependent on the frequency of that signal, f_{Sig} , and the count of the checked bits, $N_{Bit-check}$. A higher value for $N_{Bit-check}$ thereby results in a longer period for $T_{Bit-check}$ requiring a higher value for the transmitter pre-burst $T_{Preburst}$.

8.5 Receiving Mode

If the bit check was successful for all bits specified by N_{Bit-check}, the receiver switches to receiving mode. According to Figure 8-2 on page 11, the internal data signal is switched to pin DATA in that case and the data clock is available after the start bit has been detected (see Figure 9-1 on page 19). A connected microcontroller can be woken up by the negative edge at pin DATA or by the data clock at pin DATA_CLK. The receiver stays in that condition until it is switched back to polling mode explicitly.

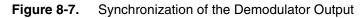
8.6 Digital Signal Processing

The data from the ASK/FSK demodulator (Dem_out) is digitally processed in different ways and as a result converted into the output signal data. This processing depends on the selected baud-rate range (BR_Range). Figure 8-7 illustrates how Dem_out is synchronized by the extended clock cycle T_{XClk} . This clock is also used for the bit-check counter. Data can change its state only after T_{XClk} has elapsed. The edge-to-edge time period t_{ee} of the Data signal as a result is always an integral multiple of T_{XClk} .

The minimum time period between two edges of the data signal is limited to $t_{ee} \ge T_{DATA_min}$. This implies an efficient suppression of spikes at the DATA output. At the same time it limits the maximum frequency of edges at DATA. This eases the interrupt handling of a connected microcontroller.

The maximum time period for DATA to stay Low is limited to $T_{DATA_L_max}$. This function is employed to ensure a finite response time in programming or switching off the receiver via pin DATA. $T_{DATA_L_max}$ is thereby longer than the maximum time period indicated by the transmitter data stream. Figure 8-9 on page 15 gives an example where Dem_out remains Low after the receiver has switched to receiving mode.

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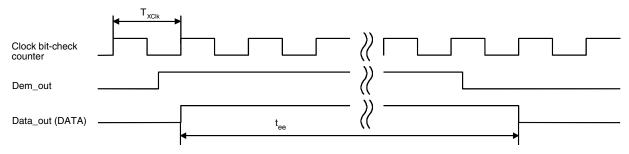


Figure 8-8. Debouncing of the Demodulator Output

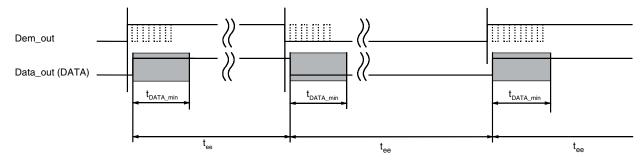
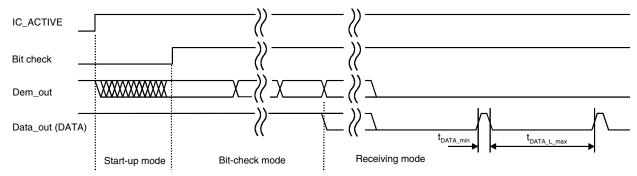


Figure 8-9. Steady L State Limited DATA Output Pattern After Transmission



After the end of a data transmission, the receiver remains active. Depending of the bit Noise_Disable in the OPMODE register, the output signal at pin DATA is high or random noise pulses appear at pin DATA (see section "Digital Noise Suppression" on page 21). The edge-to-edge time period t_{ee} of the majority of these noise pulses is equal or slightly higher than T_{DATA_min} .





8.7 Switching the Receiver Back to Sleep Mode

The receiver can be set back to polling mode via pin DATA or via pin POLLING/_ON.

When using pin DATA, this pin must be pulled to Low for the period t1 by the connected microcontroller. Figure 8-10 on page 16 illustrates the timing of the OFF command (see Figure 13-2 on page 28). The minimum value of t1 depends on BR_Range. The maximum value for t1 is not limited but it is recommended not to exceed the specified value to prevent erasing the reset marker. Note also that an internal reset for the OPMODE and the LIMIT register will be generated if t1 exceeds the specified values. This item is explained in more detail in the section "Configuration of the Receiver" on page 23. Setting the receiver to sleep mode via DATA is achieved by programming bit 1 to be '1' during the register configuration. Only one sync pulse (t3) is issued.

The duration of the OFF command is determined by the sum of t1, t2 and t10. After the OFF command the sleep time T_{Sleep} elapses. Note that the capacitive load at pin DATA is limited (see section "Data Interface" on page 29).

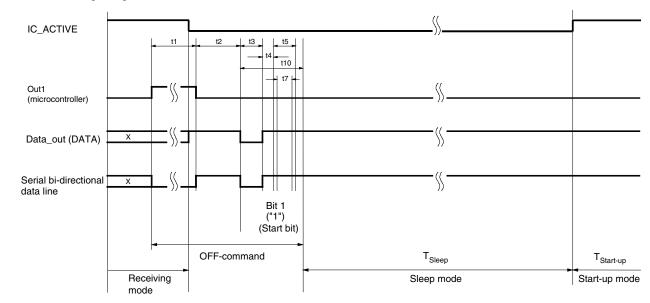
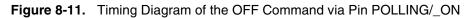


Figure 8-10. Timing Diagram of the OFF Command via Pin DATA



IC_ACTIVE	t _{on2}	t _{on3}		Bit che	ck ok
POLLING/_ON					
Data_out (DATA)	Х	»			Х
Serial bi-directional data line	x	%			X
	Receiving mode	Sleep mode	Start-up mode	Bit-check mode	Receiving mode

Figure 8-12. Activating the Receiving Mode via Pin POLLING/_ON

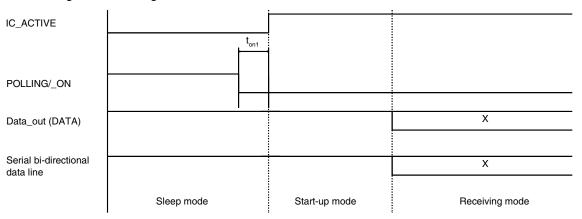


Figure 8-11 on page 16 illustrates how to set the receiver back to polling mode via pin POLL-ING/_ON. The pin POLLING/_ON must be held to low for the time period t_{on2} . After the positive edge on pin POLLING/_ON and the delay t_{on3} , the polling mode is active and the sleep time T_{Sleep} elapses.

This command is faster than using pin DATA at the cost of an additional connection to the microcontroller.

Figure 8-12 on page 17 illustrates how to set the receiver to receiving mode via the pin POLLING/_ON. The pin POLLING/_ON must be held to Low. After the delay t_{on1} , the receiver changes from sleep mode to start-up mode regardless the programmed values for T_{Sleep} and $N_{Bit-check}$. As long as POLLING/_ON is held to Low, the values for T_{Sleep} and $N_{Bit-check}$ will be ignored, but not deleted (see section "Digital Noise Suppression" on page 21).

If the receiver is polled exclusively by a microcontroller, T_{Sleep} must be programmed to 31 (permanent sleep mode). In this case the receiver remains in sleep mode as long as POLLING/_ON is held to High.





9. Data Clock

The pin DATA_CLK makes a data shift clock available to sample the data stream into a shift register. Using this data clock, a microcontroller can easily synchronize the data stream. This clock can only be used for Manchester and Bi-phase coded signals.

9.1 Generation of the Data Clock

After a successful bit check, the receiver switches from polling mode to receiving mode and the data stream is available at pin DATA. In receiving mode, the data clock control logic (Manchester/Bi-phase demodulator) is active and examines the incoming data stream. This is done, like in the bit check, by subsequent time frame checks where the distance between two edges is continuously compared to a programmable time window. As illustrated in Figure 9-1 on page 19, only two distances between two edges in Manchester and Bi-phase coded signals are valid (T and 2T).

The limits for T are the same as used for the bit check. They can be programmed in the LIMIT-register (Lim_min and Lim_max, see Table 11-10 on page 26 and Table 11-11 on page 26).

The limits for 2T are calculated as follows:

Lower limit of 2T:	Lim_min_2T = (Lim_min + Lim_max) – (Lim_max – Lim_min)/2
--------------------	--

Upper limit of 2T: Lim_max_2T= (Lim_min + Lim_max) + (Lim_max – Lim_min)/2

(If the result for 'Lim_min_2T' or 'Lim_max_2T' is not an integer value, it will be round up)

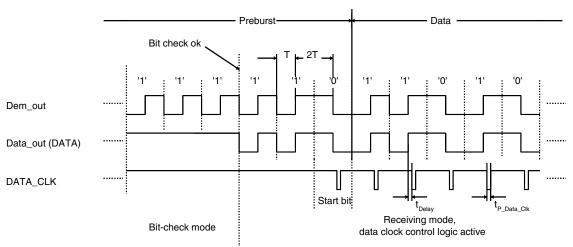
The data clock is available, after the data clock control logic has detected the distance 2T (Start bit) and is issued with the delay t_{Delay} after the edge on pin DATA (see Figure 9-1 on page 19).

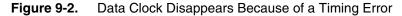
If the data clock control logic detects a timing or logical error (Manchester code violation), like illustrated in Figure 9-2 on page 19 and Figure 9-3 on page 19, it stops the output of the data clock. The receiver remains in receiving mode and starts with the bit check. If the bit check was successful and the start bit has been detected, the data clock control logic starts again with the generation of the data clock (see Figure 9-4 on page 20).

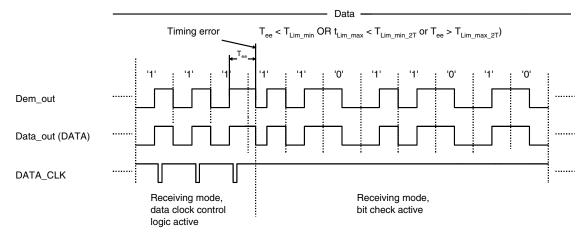
It is recommended to use the function of the data clock only in conjunction with the bit check 3, 6 or 9. If the bit check is set to 0 or the receiver is set to receiving mode via the pin POLLING/_ON, the data clock is available if the data clock control logic has detected the distance 2T (Start bit).

Note that for Bi-phase-coded signals, the data clock is issued at the end of the bit.

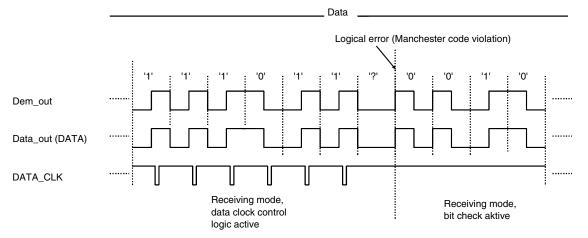








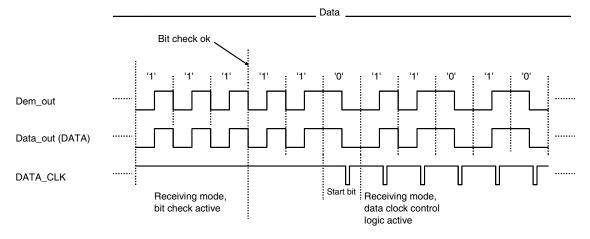








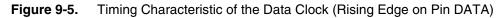


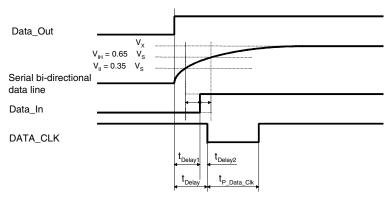


The delay of the data clock is calculated as follows: $t_{Delay} = t_{Delay1} + t_{Delay2}$

 t_{Delay1} is the delay between the internal signals Data_Out and Data_In. For the rising edge, t_{Delay1} depends on the capacitive load C_L at pin DATA and the external pull-up resistor R_{pup}. For the falling edge, t_{Delay1} depends additionally on the external voltage V_X (see Figure 9-5, Figure 9-6 on page 21 and Figure 13-2 on page 28). When the level of Data_In is equal to the level of Data_Out, the data clock is issued after an additional delay t_{Delay2} .

Note that the capacitive load at pin DATA is limited. If the maximum tolerated capacitive load at pin DATA is exceeded, the data clock disappears (see section "Data Interface" on page 29).





Data_Out Serial bi-directional data line Data_In DATA_CLK $V_{IH} = 0.65 V_S$ $V_{II} = 0.35 V_S$ $V_{II} = 0.35 V_S$

Figure 9-6. Timing Characteristic of the Data Clock (Falling Edge of the Pin DATA)

10. Digital Noise Suppression

After a data transmission, digital noise appears on the data output (see Figure 10-1 on page 21). Preventing that digital noise keeps the connected microcontroller busy. It can be suppressed in two different ways.

10.1 Automatic Noise Suppression

If the bit Noise_Disable (Table 11-9 on page 25) in the OPMODE register is set to 1 (default), the receiver changes to bit-check mode at the end of a valid data stream. The digital noise is suppressed and the level at pin DATA is High in that case. The receiver changes back to receiving mode, if the bit check was successful.

This way to suppress the noise is recommended if the data stream is Manchester or Bi-phase coded and is active after power on.

Figure 10-3 on page 22 illustrates the behavior of the data output at the end of a data stream. Note that if the last period of the data stream is a high period (rising edge to falling edge), a pulse occurs on pin DATA. The length of the pulse depends on the selected baud-rate range.

Figure 10-1. Output of Digital Noise at the End of the Data Stream

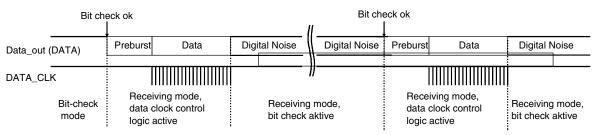






Figure 10-2. Automatic Noise Suppression

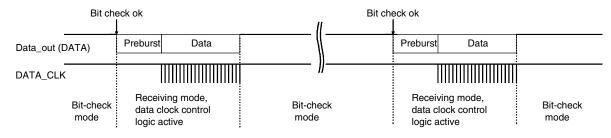
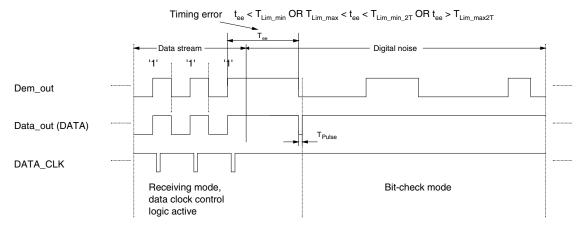


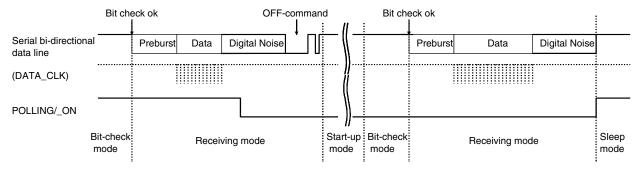
Figure 10-3. Occurrence of a Pulse at the End of the Data Stream



10.2 Controlled Noise Suppression by the Microcontroller

If the bit Noise_Disable (see Table 11-9 on page 25) in the OPMODE register is set to 0, digital noise appears at the end of a valid data stream. To suppress the noise, the pin POLLING/_ON must be set to Low. The receiver remains in receiving mode. Then, the OFF command causes the change to the start-up mode. The programmed sleep time (see Table 11-7 on page 25) will not be executed because the level at pin POLLING/_ON is low, but the bit check is active in that case. The OFF command activates the bit check also if the pin POLLING/_ON is held to Low. The receiver changes back to receiving mode if the bit check was successful. To activate the polling mode at the end of the data transmission, the pin POLLING/_ON must be set to High. This way of suppressing the noise is recommended if the data stream is not Manchester or Bi-phase coded.





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11. Configuration of the Receiver

The T5760/T5761 receiver is configured via two 12-bit RAM registers called OPMODE and LIMIT. The registers can be programmed by means of the bidirectional DATA port. If the register contents have changed due to a voltage drop, this condition is indicated by a certain output pattern called reset marker (RM). The receiver must be reprogrammed in that case. After a Power-On Reset (POR), the registers are set to default mode. If the receiver is operated in default mode, there is no need to program the registers. Table 11-3 on page 23 shows the structure of the registers. According to Table 11-2, bit 1 defines if the receiver is set back to polling mode via the OFF command (see section "Receiving Mode" on page 14) or if it is programmed. Bit 2 represents the register address. It selects the appropriate register to be programmed. To get a high programming reliability, bit 15 (Stop bit), at the end of the programming operation, must be set to 0.

Table 11-1. Effect of Bit 1 and Bit 2 on Programming the Registers

Bit 1	Bit 2	Action		
1	х	The receiver is set back to polling mode (OFF command)		
0	1	The OPMODE register is programmed		
0	0	The LIMIT register is programmed		

Table 11-2. Effect of Bit 15 on Programming the Register

Bit 15	Action			
0	The values will be written into the register (OPMODE or LIMIT)			
1	The values will not be written into the register			

Table 11-3.	Effect of the Configuration W	ords within the Registers
-------------	-------------------------------	---------------------------

Bit 1	Bit 2	Bit 3	Bit 4	Bit 5	Bit 6	Bit 7	Bit 8	Bit 9	Bit 10	Bit 11	Bit 12	Bit 13	Bit 14	Bit 15
	OFF command													
1	-	_	-	_	-	-	-	-	-	_	-	-	_	-
-	_						OPMOD	E register						-
0	1	BR_F	Range	N _{Bit-}	check	Modu-lat ion			Sleep			X _{Sleep}	Noise Suppression	0
0		Baud1	Baud0	BitChk1	BitChk0	ASK/ _FSK	Sleep4	Sleep3	Sleep2	Sleep1	Sleep0	X _{SleepStd}	Noise_ Disable	0
value	fault es of 314	0	0	0	1	0	0	0	1	1	0	0	1	_
-	_		LIMIT register					-						
				Lim_i	min					Liı	m_max			-
0	0	Lim_ min5	Lim_ min4	Lim_ min3	Lim_ min2	Lim_ min1	Lim_ min0	Lim_ max5	Lim_ max4	Lim_ max3	Lim_ max2	Lim_ max1	Lim_ max0	0
value	fault es of 314	0	1	0	1	0	1	1	0	1	0	0	1	-





The following tables illustrate the effect of the individual configuration words. The default configuration is highlighted for each word.

BR_Range sets the appropriate baud-rate range and simultaneously defines XLim. XLim is used to define the bit-check limits T_{Lim_min} and T_{Lim_max} as shown in Table 11-10 on page 26 and Table 11-11 on page 26.

BR_Range		
Baud1	Baud0	Baud-rate Range/Extension Factor for Bit-check Limits (XLim)
0	0	BR_Range0 (application USA/Europe: BR_Range0 = 1.0 kBaud to 1.8 kBaud) XLim = 8 (default)
0	1	BR_Range1 (application USA/Europe: BR_Range1 = 1.8 kBaud to 3.2 kBaud) XLim = 4
1	0	BR_Range2 (application USA/Europe: BR_Range2 = 3.2 kBaud to 5.6 kBaud) XLim = 2
1	1	BR_Range3 (Application USA/Europe: BR_Range3 = 5.6 kBaud to 10 kBaud) XLim = 1

 Table 11-4.
 Effect of the configuration word BR_Range

Table 11-5.	Effect of the	Configuration	word N _{Bit-check}
-------------	---------------	---------------	-----------------------------

N _{Bit-}	check	
BitChk1	BitChk0	Number of Bits to be Checked
0	0	0
0	1	3 (default)
1	0	6
1	1	9

 Table 11-6.
 Effect of the Configuration Bit Modulation

Modulation	Selected Modulation
ASK/_FSK	_
0	FSK (default)
1	ASK

		Sleep			Start Value for Sleep Counter
Sleep4	Sleep3	Sleep2	Sleep1	Sleep0	$(T_{Sleep} = Sleep \times X_{Sleep} \times 1024 \times T_{Clk})$
0	0	0	0	0	0 (Receiver is continuously polling until a valid signal occurs)
0	0	0	0	1	$ \begin{array}{l} 1 \ (T_{Sleep} \approx \ 2.1 \ ms \ for \ X_{Sleep} = 1 \ and \\ f_{RF} = 868.3 \ ms, \approx \ 2.0 \ ms \ for \ f_{RF} = 915 \ MHz) \end{array} $
0	0	0	1	0	2
0	0	0	1	1	3
0	0	1	1	0	6 (T _{Sleep} = 12.695 ms for f_{RF} = 868.3 MHz, 12.047 ms for f_{RF} = 915 MHz) (default)
1	1	1	0	1	29
1	1	1	1	0	30
1	1	1	1	1	31 (permanent sleep mode)

Table 11-7. Effect of the Configuration Word Sleep

 Table 11-8.
 Effect of the Configuration Bit XSleep

X _{Sleep} X _{SleepStd}	Extension Factor for Sleep Time (T _{Sleep} = Sleep × X_{Sleep} × 1024 × T _{Clk})
0	1 (default)
1	8

Table 11-9.	Effect of the Configuration Bit Noise Sup	pression

Noise Suppression						
Noise_Disable	Suppression of the Digital Noise at Pin DATA					
0	Noise suppression is inactive					
1	Noise suppression is active (default)					





	Lim_mi	n ⁽¹⁾ (Lim_min -	< 10 is not App	olicable)		Lower Limit Value for Bit Check
Lim_min5	Lim_min4	Lim_min3	Lim_min2	Lim_min1	Lim_min0	$(T_{Lim_{min}} = Lim_{min} \times XLim \times T_{Clk})$
0	0	1	0	1	0	10
0	0	1	0	1	1	11
0	0	1	1	0	0	12
0	1	0	1	0	1	21 (default) ($T_{Lim_{min}} = 347 \ \mu s$ for $f_{RF} = 868.3 \ MHz$ and BR_Range0 $T_{Lim_{min}} = 329 \ \mu s$ for $f_{RF} = 915 \ MHz$ and BR_Range0)
1	1	1	1	0	1	61
1	1	1	1	1	0	62
1	1	1	1	1	1	63

Table 11-10. Effect of the Configuration Word Lim_min

Note: 1. Lim_min is also used to determine the margins of the data clock control logic (see section "Data Clock" on page 18).

Table 11-11. Effect of the Configuration Word Lim_max

	Lim_ma	x ⁽¹⁾ (Lim_max	Upper Limit Value for Bit Check			
Lim_max5	Lim_max4	Lim_max3	Lim_max2	nax2 Lim_max1 Lim_max0		(TLim_max = (Lim_max – 1) \times XLim \times T _{Clk})
0	0	1	1	0	0	12
0	0	1	1	0	1	13
0	0	1	1	1	0	14
1	0	1	0	0	1	41 (default) (TLim_max = 661 μ s for f _{RF} = 868.3 MHz and BR_Range0, TLim_max = 627 μ s for f _{RF} = 915 MHz and BR_Range0)
1	1	1	1	0	1	61
1	1	1	1	1	0	62
1	1	1	1	1	1	63

Note: 1. Lim_max is also used to determine the margins of the data clock control logic (see section "Data Clock" on page 18).

12. Conservation of the Register Information

The ATA5760/ATA5761 implies an integrated power-on reset and brown-out detection circuitry to provide a mechanism to preserve the RAM register information.

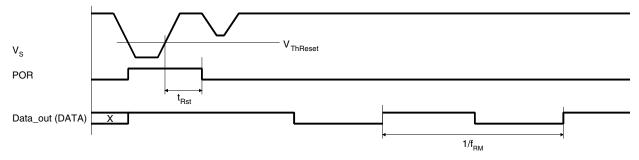
According to Figure 12-1, a power-on reset (POR) is generated if the supply voltage V_S drops below the threshold voltage $V_{ThReset}$. The default parameters are programmed into the configuration registers in that condition. Once V_S exceeds $V_{ThReset}$ the POR is canceled after the minimum reset period t_{Rst} . A POR is also generated when the supply voltage of the receiver is turned on.

To indicate that condition, the receiver displays a reset marker (RM) at pin DATA after a reset. The RM is represented by the fixed frequency f_{RM} at a 50% duty-cycle. RM can be canceled via a Low pulse t1 at pin DATA. The RM implies the following characteristics:

- f_{RM} is lower than the lowest feasible frequency of a data signal. By this means, RM cannot be misinterpreted by the connected microcontroller.
- If the receiver is set back to polling mode via pin DATA, RM cannot be canceled by accident if t1 is applied according to the proposal in the section "Programming the Configuration Register" on page 28.

By means of that mechanism the receiver cannot lose its register information without communicating that condition via the reset marker RM.









13. Programming the Configuration Register

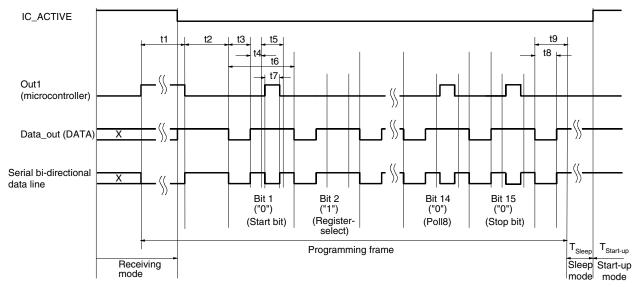
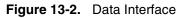
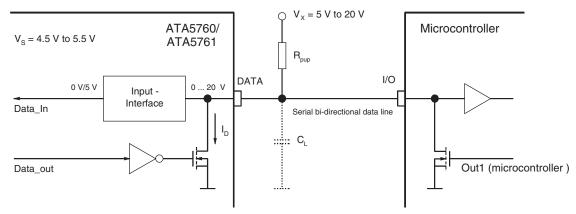


Figure 13-1. Timing of the Register Programming





The configuration registers are programmed serially via the bi-directional data line according to Figure 13-1 and Figure 13-2.

To start programming, the serial data line DATA is pulled to Low for the time period t1 by the microcontroller. When DATA has been released, the receiver becomes the master device. When the programming delay period t2 has elapsed, it emits 15 subsequent synchronization pulses with the pulse length t3. After each of these pulses, a programming window occurs. The delay until the program window starts is determined by t4, the duration is defined by t5. Within the programming window, the individual bits are set. If the microcontroller pulls down pin DATA for the time period t7 during t5, the according bit is set to '0'. If no programming pulse t7 is issued, this bit is set to '1'. All 15 bits are subsequently programmed this way. The time frame to program a bit is defined by t6.

Bit 15 is followed by the equivalent time window t9. During this window, the equivalence acknowledge pulse t8 (E_Ack) occurs if the just programmed mode word is equivalent to the mode word that was already stored in that register. E_Ack should be used to verify that the mode word was correctly transferred to the register. The register must be programmed twice in that case.

Programming of a register is possible both in sleep-mode and in active-mode of the receiver.

During programming, the LNA, LO, lowpass filter IF-amplifier and the FSK/ASK Manchester demodulator are disabled.

The programming start pulse t1 initiates the programming of the configuration registers. If bit 1 is set to '1', it represents the OFF command to set the receiver back to polling mode at the same time. For the length of the programming start pulse t1, the following convention should be considered:

• t1(min) < t1 < 5632 T_{Clk}:

t1(min) is the minimum specified value for the relevant BR_Range

Programming respectively OFF command is initiated if the receiver is not in reset mode. If the receiver is in reset mode, programming respectively Off command is not initiated and the reset marker RM is still present at pin DATA.

This period is generally used to switch the receiver to polling mode or to start the programming of a register. In reset condition, RM is not cancelled by accident.

• t1 > 7936 × T_{Clk}

Programming respectively OFF command is initiated in any case. The registers OPMODE and LIMIT are set to the default values. RM is cancelled if present.

This period is used if the connected microcontroller detected RM. If the receiver operates in default mode, this time period for t1 can generally be used.

Note that the capacitive load at pin DATA is limited.

14. Data Interface

The data interface (see Figure 13-2 on page 28) is designed for automotive requirements. It can be connected via the pull-up resistor R_{pup} up to 20V and is short-circuit-protected.

The applicable pull-up resistor R_{pup} depends on the load capacity C_L at pin DATA and the selected BR_range (see Table 14-1).

-	BR_range	Applicable R _{pup}
	В0	1.6 k Ω to 47 k Ω
C < 1nE	B1	1.6 kΩ to 22 kΩ
C _L ≤1nF	B2	1.6 kΩ to 12 kΩ
	B3	1.6 k Ω to 5.6 k Ω
	В0	1.6 kΩ to 470 kΩ
C <100pE	B1	1.6 kΩ to 220 kΩ
$C_L \leq 100 pF$	B2	1.6 kΩ to 120 kΩ
	B3	1.6 kΩ to 56 kΩ

Table 14-1.Applicable R





Figure 14-1. Application Circuit: f_{RF} = 868.3 MHz without SAW Filter

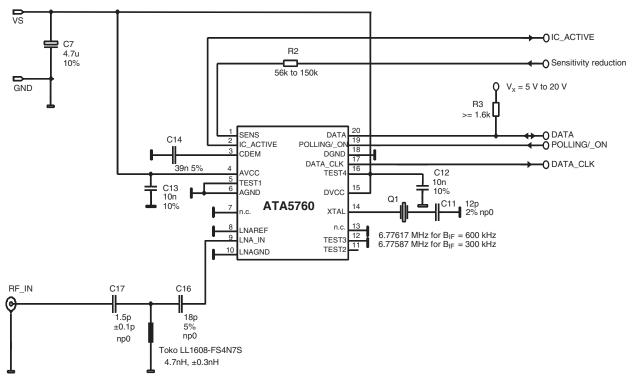
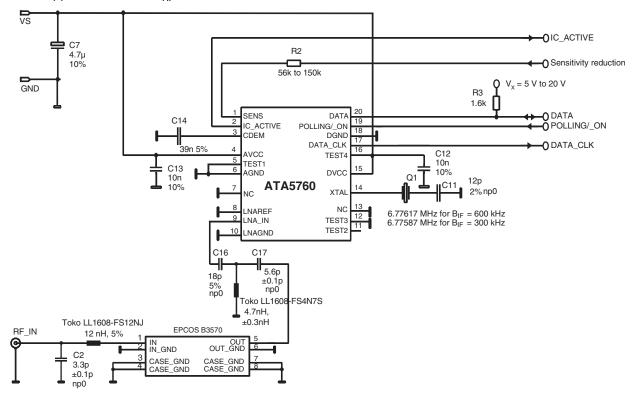


Figure 14-2. Application Circuit: f_{RF} = 868.3 MHz with SAW Filter



15. Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameters	Symbol	Min.	Max.	Unit
Supply voltage	Vs		6	V
Power dissipation	P _{tot}		1000	mW
Junction temperature	Т _ј		150	°C
Storage temperature	T _{stg}	-55	+125	°C
Ambient temperature	T _{amb}	-40	+105	°C
Maximum input level, input matched to 50Ω	P _{in_max}		10	dBm

16. Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient	R _{thJA}	100	K/W

17. Electrical Characteristics

All parameters refer to GND, $T_{amb} = -40^{\circ}$ C to +105°C, $V_{S} = 4.5$ V to 5.5V, $f_{0} = 868.3$ MHz and $f_{0} = 915$ MHz, unless otherwise specified. (For typical values: $V_{S} = 5$ V, $T_{amb} = 25^{\circ}$ C)

			f _{RF}	= 868.3	MHz	f _{RF} = 915 MHz			Variable Oscillator			
Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Basic Clock	Cycle of the Digit	al Circuitry									÷	
Basic clock cycle		T _{Clk}	2.0662		2.0662	1.9607		1.9607	14/f _{XTO}		14/f _{XTO}	μs
Extended basic clock cycle	BR_Range0 BR_Range1 BR_Range2 BR_Range3	T _{XClk}	16.53 8.26 4.13 2.07		16.53 8.26 4.13 2.07	15.69 7.84 3.92 1.96		15.69 7.84 3.92 1.96	$\begin{array}{c} 8\times T_{Clk} \\ 4\times T_{Clk} \\ 2\times T_{Clk} \\ 1\times T_{Clk} \end{array}$		$\begin{array}{c} 8\times T_{Clk} \\ 4\times T_{Clk} \\ 2\times T_{Clk} \\ 1\times T_{Clk} \end{array}$	μs μs μs μs
Polling Mode	•		1	1	I	I	1	l			1	
Sleep time (see Figure 8-4 on page 13, Figure 9-1 on page 19 and Figure 14-1 on page 30)	Sleep and XSleep are defined in the OPMODE register	T _{Sleep}	Sleep × X _{Sleep} × 1024 × 2.0662		Sleep × X _{Sleep} × 1024 × 2.0662	Sleep × X _{Sleep} × 1024 × 1.9607		Sleep × X _{Sleep} × 1024 × 1.9607	$\frac{\text{Sleep} \times}{\text{X}_{\text{Sleep}} \times} \\ 1024 \times \text{T}_{\text{Clk}}$		$Sleep \times \\ X_{Sleep} \times \\ 1024 \times T_{Clk}$	ms
Start-up time (see Figure 8-4 on page 13 and Figure 8-5 on page 13)	BR_Range2	T _{Startup}	1852 1059 1059 662		1852 1059 1059 662	1758 1049 1049 628		1758 1049 1049 628	896.5 512.5 512.5 320.5 × T _{Clk}		896.5 512.5 512.5 320.5 × T _{Clk}	μs μs μs μs





17. Electrical Characteristics (Continued) All parameters refer to GND, $T_{amb} = -40^{\circ}$ C to $+105^{\circ}$ C, $V_{S} = 4.5$ V to 5.5V, $f_{0} = 868.3$ MHz and $f_{0} = 915$ MHz, unless otherwise specified. (For typical values: $V_{S} = 5$ V, $T_{amb} = 25^{\circ}$ C)

			f _{RF} = 868.3 MHz			f _{RF} = 915 MHz			Variable Oscillator			
Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Time for bit check (see Figure 8-4 on page 13)	Average bit-check time while polling, no RF applied (see Figure 8-8 on page 15 and Figure 8-9 on page 15) BR_Range0 BR_Range1 BR_Range2 BR_Range3	T _{Bit-check}		0.45 0.24 0.14 0.08			0.45 0.24 0.14 0.08					ms ms ms
Time for bit check (see Figure 8-4 on page 13)	$\begin{array}{l} \mbox{Bit-check time} \\ \mbox{for a valid input} \\ \mbox{signal } f_{Sig} \mbox{(see} \\ \mbox{Figure 8-5 on} \\ \mbox{page 13)} \\ \mbox{N}_{Bit-check} = 0 \\ \mbox{N}_{Bit-check} = 3 \\ \mbox{N}_{Bit-check} = 6 \\ \mbox{N}_{Bit-check} = 9 \end{array}$	T _{Bit-check}	3/f _{Sig} 6/f _{Sig} 9/f _{Sig}		3.5/f _{Sig} 6.5/f _{Sig} 9.5/f _{Sig}	3/f _{Sig} 6/f _{Sig} 9/f _{Sig}		3.5/f _{Sig} 6.5/f _{Sig} 9.5/f _{Sig}	$\begin{array}{c} 1\times T_{XClk}\\ 3/f_{Sig}\\ 6/f_{Sig}\\ 9/f_{Sig} \end{array}$		$\begin{array}{l} 1\times T_{Clk}\\ 3.5/f_{Sig}\\ 6.5/f_{Sig}\\ 9.5/f_{Sig} \end{array}$	ms ms ms
Receiving Mo	ode											
Intermediate frequency		f _{IF}		0.95			1.00		f _{RF} /915			MHz
Baud-rate range	BR_Range0 BR_Range1 BR_Range2 BR_Range3	BR_Range	1.0 1.8 3.2 5.6		1.8 3.2 5.6 10.0	1.054 1.89 3.38 5.9		1.89 3.38 5.9 10.5	BR_Range0 × 2 µs/T _{Clk} BR_Range1 × 2 µs/T _{Clk} BR_Range2 × 2 µs/T _{Clk} BR_Range3 × 2 µs/T _{Clk}			kBauc kBauc kBauc kBauc
Minimum time period between edges at pin DATA (see Figure 8-11 and Figure 8-12 on page 17) (With the exception of parameter T _{Pulse})	BR_Range = BR_Range0 BR_Range1 BR_Range2 BR_Range3	t _{DATA_min}	165.3 82.6 41.3 20.7		165.3 82.6 41.3 20.7	156.8 78.4 39.2 19.6		156.8 78.4 39.2 19.6	$\begin{array}{l} 10 \times T_{XClk} \\ 10 \times T_{XClk} \\ 10 \times T_{XClk} \\ 10 \times T_{XClk} \end{array}$		$\begin{array}{l} 10 \times T_{XClk} \\ 10 \times T_{XClk} \\ 10 \times T_{XClk} \\ 10 \times T_{XClk} \\ 10 \times T_{XClk} \end{array}$	μs μs μs
Maximum Low period at pin DATA (see Figure 8-9 on page 15)	BR_Range0 BR_Range1	t _{DATA_L_max}	2149 1074 537 269		2149 1074 537 269	2139 1020 510 255		2139 1020 510 255	$\begin{array}{c} 130 \times T_{XClk} \\ 130 \times T_{XClk} \\ 130 \times T_{XClk} \\ 130 \times T_{XClk} \\ 130 \times T_{XClk} \end{array}$		$\begin{array}{c} 130 \times T_{XClk} \\ 130 \times T_{XClk} \\ 130 \times T_{XClk} \\ 130 \times T_{XClk} \\ 130 \times T_{XClk} \end{array}$	μs
Delay to activate the start-up mode (see Figure 9-3 on page 19)		Ton1	19.6		21.7	18.6		20.6	$9.5 imes T_{Clk}$		$10.5 imes T_{Clk}$	μs

17. Electrical Characteristics (Continued)

All parameters refer to GND, $T_{amb} = -40^{\circ}$ C to $+105^{\circ}$ C, $V_{S} = 4.5$ V to 5.5V, $f_{0} = 868.3$ MHz and $f_{0} = 915$ MHz, unless otherwise specified. (For typical values: $V_{S} = 5$ V, $T_{amb} = 25^{\circ}$ C)

			f _{RF} = 868.3 MHz		f _{RF} = 915 MHz			Variable Oscillator				
Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
OFF command at pin POLLING/_O N (see Figure 9-2 on page 19)		Ton2	16.5			15.6			$8 imes T_{Clk}$			μs
Delay to activate the sleep mode (see Figure 9-2 on page 19)		Ton3	17.6		19.6	16.6		18.6	$8.5 imes T_{Clk}$		$9.5 imes T_{Clk}$	μs
Pulse on pin DATA at the end of a data stream (see Figure 12-1 on page 27)	BR_Range = BR_Range0 BR_Range1 BR_Range2 BR_Range3	T _{Pulse}	16.5 8.3 4.1 2.1		16.5 8.3 4.1 2.1	15.69 7.84 3.92 1.96		15.69 7.84 3.92 1.96	$\begin{array}{l} 8 \times T_{Clk} \\ 4 \times T_{Clk} \\ 2 \times T_{Clk} \\ 1 \times T_{Clk} \end{array}$		$\begin{array}{l} 8\times T_{Clk} \\ 4\times T_{Clk} \\ 2\times T_{Clk} \\ 1\times T_{Clk} \end{array}$	μs μs μs μs
Configuration	n of the Receiver	(see Figure	8-10 on pa	age 16 ai	nd Figure	14-1 on pa	ge 30)					
Frequency of the reset marker	Frequency is stable within 50 ms after POR	f _{RM}	118.2		118.2	124.5		124.5	1/ (4096 × T _{Clk})		1/ (4096 × T _{Clk})	Hz
Programming start pulse	BR_Range = BR_Range0 BR_Range1 BR_Range2 BR_Range3 after POR	t1	3355 2273 1731 1461 16397		11637 11637 11637 11637	3184 2168 1643 1386 15560		11043 11043 11043 11043 11043	$\begin{array}{c} 1624 \times \ T_{Clk} \\ 1100 \times \ T_{Clk} \\ 838 \times \ T_{Clk} \\ 707 \times \ T_{Clk} \\ 7936 \times \ T_{Clk} \end{array}$		$\begin{array}{c} 5632 \times T_{Clk} \\ 5632 \times T_{Clk} \\ 5632 \times T_{Clk} \\ 5632 \times T_{Clk} \\ 5632 \times T_{Clk} \end{array}$	μs μs μs μs
Programming delay period		t2	795		797	754		756	$\rm 384.5 \times T_{Clk}$		$385.5 imes T_{Clk}$	μs
Synchroni-zat ion pulse		t3	264		264	251		251	$128 imes T_{Clk}$		$\rm 128 \times T_{Clk}$	μs
Delay until of the program window starts		t4	131		131	125		125	$63.5 imes T_{Clk}$		$63.5 imes T_{Clk}$	μs
Programming window		t5	529		529	502		502	$256 imes T_{Clk}$		$256 imes T_{Clk}$	μs
Time frame of a bit		t6	1058		1058	1004		1004	$512 imes T_{Clk}$		$512 imes T_{Clk}$	μs
Programming pulse		t7	132		529	125		502	$64\times \mathrm{T_{Clk}}$		$256 \times T_{\text{Clk}}$	μs
Equivalent acknowledge pulse: E_Ack		t8	264		264	251		251	$128 \times T_{\text{Clk}}$		$128 imes T_{Clk}$	μs
Equivalent time window		t9	533		533	506		506	$258 imes T_{Clk}$		$258 imes T_{Clk}$	μs
OFF-bit programming window		t10	929		929	881		881	$449.5 imes T_{Clk}$		$449.5 imes T_{Clk}$	μs





17. Electrical Characteristics (Continued)

All parameters refer to GND, $T_{amb} = -40^{\circ}$ C to $+105^{\circ}$ C, $V_{S} = 4.5$ V to 5.5V, $f_{0} = 868.3$ MHz and $f_{0} = 915$ MHz, unless otherwise specified. (For typical values: $V_{S} = 5$ V, $T_{amb} = 25^{\circ}$ C)

			f _{RF} = 868.3 MHz		f _{RF} = 915 MHz		Variable Oscillator					
Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Data Clock (s	see Figure 10-2 o	n page 22 an	d Figure 1	0-3 on p	age 22)							<u>, i </u>
delay time between edge at DATA	BR_Range = BR_Range0 BR_Range1 BR_Range2 BR_Range3	t _{Delay2}	0 0 0 0		16.5 8.3 4.1 2.1	0 0 0 0		16.7 7.8 3.9 1.96	0 0 0 0		$\begin{array}{l} 1 \times T_{XClk} \\ 1 \times T_{XClk} \\ 1 \times T_{XClk} \\ 1 \times T_{XClk} \\ 1 \times T_{XClk} \end{array}$	μs μs μs μs
Pulse width of negative pulse at pin	BR_Range = BR_Range0 BR_Range1 BR_Range2 BR_Range3	t _{P_DATA_CLK}	66.1 33.0 16.5 8.3		66.1 33.0 16.5 8.3	63 31 15.7 7.8		63 31 15.7 7.8	$\begin{array}{c} 4 \times T_{XClk} \\ 4 \times T_{XClk} \\ 4 \times T_{XClk} \\ 4 \times T_{XClk} \end{array}$		$\begin{array}{c} 4\times T_{XClk} \\ 4\times T_{XClk} \\ 4\times T_{XClk} \\ 4\times T_{XClk} \end{array}$	μs μs μs μs

18. Electrical Characteristics (continued)

All parameters refer to GND, $T_{amb} = -40^{\circ}$ C to $+105^{\circ}$ C, $V_{S} = 4.5$ V to 5.5V, $f_{0} = 868.3$ MHz and $f_{0} = 915$ MHz, unless otherwise specified. (For typical values: $V_{S} = 5$ V, $T_{amb} = 25^{\circ}$ C)

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
	Sleep mode (XTO and polling logic active)	IS _{off}		170	276	μA
Current consumption	IC active (start-up-, bit-check-, receiving mode) Pin DATA = H FSK ASK	IS _{on}		7.8 7.4	9.9 9.6	mA mA
LNA, Mixer, Polyphase Lowp	ass and IF Amplifier (Input Matched Acco	rding to Figu	re 14-1 on	page 30 Refe	erred to R	FIN)
Third-order intercept point	LNA/mixer/IF amplifier	IIP3		-16		dBm
LO spurious emission	Required according to I-ETS 300220	IS _{LORF}		-70	-57	dBm
System noise figure	With power matching S11 < -10 dB	NF		5		dB
LNA_IN input impedance	At 868.3 MHz At 915 MHz	Zi _{LNA_IN}		200 3.2 200 3.2		Ω∥pF Ω∥pF
1 dB compression point		IP _{1db}		-25		dBm
Image rejection	Within the complete image band		20	30		dB
Maximum input level	BER ≤ 10 ⁻³ , FSK mode ASK mode	P _{in_max}			-10 -10	dBm dBm

18. Electrical Characteristics (continued)

All parameters refer to GND, $T_{amb} = -40^{\circ}$ C to $+105^{\circ}$ C, $V_{S} = 4.5$ V to 5.5V, $f_{0} = 868.3$ MHz and $f_{0} = 915$ MHz, unless otherwise specified. (For typical values: $V_{S} = 5$ V, $T_{amb} = 25^{\circ}$ C)

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Local Oscillator	· · ·					
Operating frequency range VCO	T5760 T5761	f _{VCO} f _{VCO}	866 900		871 929	MHz MHz
Phase noise local oscillator	f _{osc} = 867.3 MHz at 10 MHz	L (fm)		-140	-130	dBC/Hz
Spurious of the VCO	At ±f _{XTO}			-55	-45	dBC
XTO pulling	XTO pulling, appropriate load capacitance must be connected to XTAL, crystal $C_M = 7$ fF	f _{xto}	–30ppm	f _{XTAL}	+30ppm	MHz
Series resonance resistor of the crystal	Parameter of the supplied crystal	R _s			120	Ω
Static capacitance at pin XTAL to GND	Parameter of the supplied crystal and board parasitics	C ₀			6.5	pF
Analog Signal Processing (Input I	Matched According to Figure 14-1 on	page 30 Ref	erred to RF	N)		L
Input sensitivity ASK	ASK (level of carrier) 300 kHz IF-filter BER $\leq 10^{-3}$, 100% Mod f _{in} = 868.3 MHz/915 MHz V _S = 5V, T _{amb} = 25°C f _{IF} = 950 kHz/1 MHz	P _{Ref_ASK}				
	BR_Range0		-111	-113	-115	dBm
	BR_Range1		-109	-111	-113	dBm
	BR_Range2		-108	-110	-112	dBm
	BR_Range3		-106	-108	-110	dBm
Input sensitivity ASK	ASK (level of carrier) 600 kHz IF-filter BER $\leq 10^{-3}$, 100% Mod f _{in} = 868.3 MHz/915 MHz V _S = 5V, T _{amb} = 25°C f _{IF} = 950 kHz/1 MHz	P _{Ref_ASK}				
	BR_Range0	107.011	-110	-112	-114	dBm
	BR_Range1		-108.5	-110.5	-112.5	dBm
	BR_Range2		-108	-110	-112	dBm
	BR_Range3		-106	-108	-110	dBm
Sensitivity variation ASK for the full operating range compared to $T_{amb} = 25^{\circ}C$, $V_{S} = 5V$		ΔP_{Ref}	+2.5		-1.0	dB





18. Electrical Characteristics (continued) All parameters refer to GND, $T_{amb} = -40^{\circ}$ C to $+105^{\circ}$ C, $V_{S} = 4.5$ V to 5.5V, $f_{0} = 868.3$ MHz and $f_{0} = 915$ MHz, unless otherwise specified. (For typical values: $V_{S} = 5$ V, $T_{amb} = 25^{\circ}$ C)

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Sensitivity variation ASK for full	$\begin{array}{l} 300 \text{ kHz version} \\ f_{in} = 868.3 \text{ MHz}/915 \text{ MHz} \\ f_{IF} = 950 \text{ kHz}/989 \text{ kHz}/1 \text{ MHz} \\ f_{IF} -110 \text{ kHz to +110 kHz} \\ f_{IF} -140 \text{ kHz to +140 kHz} \\ P_{ASK} = P_{Ref_ASK} + \Delta P_{Ref} \end{array}$	ΔP_{Ref}	+5.5 +7.5		-1.5 -1.5	dB dB
compared to $T_{amb} = 25$ C, $V_S = 5V$	$\begin{array}{l} \label{eq:1.1} 600 \text{ kHz version} \\ f_{in} = 868.3 \text{ MHz}/915 \text{ MHz} \\ f_{IF} = 950 \text{ kHz}/989 \text{ kHz}/1 \text{ MHz} \\ f_{IF} -210 \text{ kHz to } +210 \text{ kHz} \\ f_{IF} -270 \text{ kHz to } +270 \text{ kHz} \\ P_{ASK} = P_{Ref_ASK} + \Delta P_{Ref} \end{array}$	ΔP_{Ref}	+5.5 +7.5		-1.5 -1.5	dB dB
	$\begin{array}{l} \text{BER} \leq \ 10^{-3} \\ \text{f}_{\text{in}} = \ 868.3 \ \text{MHz}/915 \ \text{MHz} \\ \text{V}_{\text{S}} = \ 5\text{V}, \ \text{T}_{\text{amb}} = \ 25^{\circ}\text{C} \\ \text{f}_{\text{IF}} = \ 950 \ \text{kHz}/989 \ \text{kHz}/1 \ \text{MHz} \end{array}$					
	BR_Range0 df = ± 16 kHz to ± 28 kHz df = ± 10 kHz to ± 100 kHz	P _{Ref_FSK}	-103 -101	-106	-107.5 -107.5	dBm dBm
Input sensitivity FSK 300 kHz and 600 kHz version	BR_Range1 df = ± 16 kHz to ± 28 kHz df = ± 10 kHz to ± 100 kHz	P _{Ref_FSK}	-101 -99	-104	-105.5 -105.5	dBm dBm
	BR_Range2 df = ±18 kHz to ±31 kHz df = ±13 kHz to ±100 kHz	P _{Ref_FSK}	-99.5 -97.5	-102.5	-104	dBm dBm
	BR_Range3 df = ± 25 kHz to ± 44 kHz df = ± 20 kHz to ± 100 kHz	P _{Ref_FSK}	-97.5 -95.5	-100.5	-102	dBm dBm
Sensitivity variation FSK for the full operating range compared to $T_{amb} = 25^{\circ}C$, $V_{S} = 5V$	$ \begin{array}{l} f_{\text{in}} = 868.3 \ \text{MHz}/915 \ \text{MHz} \\ f_{\text{IF}} = 950 \ \text{kHz}/989 \ \text{kHz}/1 \ \text{MHz} \\ P_{\text{FSK}} = P_{\text{Ref}_{\text{FSK}}} + \Delta P_{\text{Ref}} \end{array} $	ΔP_{Ref}	+3		-1.5	dB
Sensitivity variation FSK for the full operating range including IF filter compared to $T_{amb} = 25^{\circ}C$, $V_{S} = 5V$	$\begin{array}{l} 300 \text{ kHz version} \\ f_{in} = 868.3 \text{ MHz}/915 \text{ MHz} \\ f_{IF} = 950 \text{ kHz}/989 \text{ kHz}/1 \text{ MHz} \\ f_{IF} -110 \text{ kHz to +110 kHz} \\ f_{IF} -140 \text{ kHz to +140 kHz} \\ f_{IF} -180 \text{ kHz to +180 kHz} \\ P_{FSK} = P_{Ref_FSK} + \Delta P_{Ref} \end{array}$	ΔP_{Ref}	+6 +8 +11		-2 -2 -2	dB dB dB
	$\begin{array}{l} \label{eq:1.1} 600 \text{ kHz version} \\ f_{in} = 868.3 \text{ MHz}/915 \text{ MHz} \\ f_{IF} = 950 \text{ kHz}/989 \text{ kHz}/1 \text{ MHz} \\ f_{IF} -150 \text{ kHz to +150 kHz} \\ f_{IF} -200 \text{ kHz to +200 kHz} \\ f_{IF} -200 \text{ kHz to +200 kHz} \\ f_{IF} -260 \text{ kHz to +260 kHz} \\ P_{FSK} = P_{Ref_FSK} + \Delta P_{Ref} \end{array}$	ΔP_{Ref}	+6 +8 +11		-2 -2 -2	dB dB dB
S/N ratio to suppress inband noise signals. Noise signals may have any modulation scheme	ASK mode FSK mode	SNR _{ASK} SNR _{FSK}		10 2	12 3	dB dB
Dynamic range RSSI amplifier		ΔR_{RSSI}		60		dB

18. Electrical Characteristics (continued)

All parameters refer to GND, $T_{amb} = -40^{\circ}$ C to $+105^{\circ}$ C, $V_{S} = 4.5$ V to 5.5V, $f_{0} = 868.3$ MHz and $f_{0} = 915$ MHz, unless otherwise specified. (For typical values: $V_{S} = 5$ V, $T_{amb} = 25^{\circ}$ C)

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Lower cut-off frequency of the data filter	$f_{cu_DF} = \frac{1}{2 \times \pi \times 30 \text{ k}\Omega \times \text{CDEM}}$ CDEM = 33 nF	fcu_DF	0.11	0.16	0.20	kHz
Recommended CDEM for best performance	BR_Range0 (default) BR_Range1 BR_Range2 BR_Range3	CDEM		39 22 12 8.2		nF nF nF nF
Edge-to-edge time period of the input data signal for full sensitivity	BR_Range0 (default) BR_Range1 BR_Range2 BR_Range3	t _{ee_sig}	270 156 89 50		1000 560 320 180	µs µs µs µs
Upper cut-off frequency data filter	Upper cut-off frequency programmable in 4 ranges via a serial mode word BR_Range0 (default) BR_Range1 BR_Range2 BR_Range3	fu	2.8 4.8 8.0 15.0	3.4 6.0 10.0 19.0	4.0 7.2 12.0 23.0	kHz kHz kHz kHz
	$\begin{array}{l} 300 \text{ kHz IF-filter} \\ \text{R}_{\text{Sense}} \text{ connected from pin Sens} \\ \text{to } \text{V}_{\text{S}}, \text{ input matched according to} \\ \text{Figure 14-1 on page 30,} \\ \text{f}_{\text{in}} = 868.3 \text{ MHz/915 MHz,} \\ \text{V}_{\text{S}} = 5\text{V}, \text{T}_{\text{amb}} = +25^{\circ}\text{C} \end{array}$					dBm (peak level)
	$R_{Sense} = 56 \ k\Omega$	P_{Ref_Red}	-67	-72	-77	dBm
Deduced consitivity	$R_{Sense} = 100 \text{ k}\Omega$	P_{Ref_Red}	-76	-81	-86	dBm
Reduced sensitivity	600 kHz IF-filter R_{Sense} connected from pin Sens to V _S , input matched according to Figure 14-1 on page 30, $f_{in} = 868.3 \text{ MHz/915 MHz},$ $V_S = 5V, T_{amb} = +25^{\circ}\text{C}$					dBm (peak level)
	$R_{\text{Sense}} = 56 \text{ k}\Omega$	P _{Ref_Red}	-63	-68	-73	dBm
	$R_{\text{Sense}} = 100 \text{ k}\Omega$	P _{Ref_Red}	-72	-77	-82	dBm
Reduced sensitivity variation over full operating range	$R_{Sense} = 56 kΩ$ $R_{Sense} = 100 kΩ$ $P_{Red} = P_{Ref Red} + ΔP_{Red}$	ΔP_{Red}	5 5	0 0	0 0	dB dB
Reduced sensitivity variation for different values of R _{Sense}	Values relative to $R_{Sense} = 56 \text{ k}\Omega$ $R_{Sense} = 56 \text{ k}\Omega$ $R_{Sense} = 68 \text{ k}\Omega$ $R_{Sense} = 82 \text{ k}\Omega$ $R_{Sense} = 100 \text{ k}\Omega$ $R_{Sense} = 120 \text{ k}\Omega$ $R_{Sense} = 150 \text{ k}\Omega$ $P_{Red} = P_{Ref_Red} + \Delta P_{Red}$	ΔP_{Red}		0 -3.5 -6.0 -9.0 -11.0 -13.5		dB dB dB dB dB dB
Threshold voltage for reset		V _{ThRESET}	1.95	2.8	3.75	V





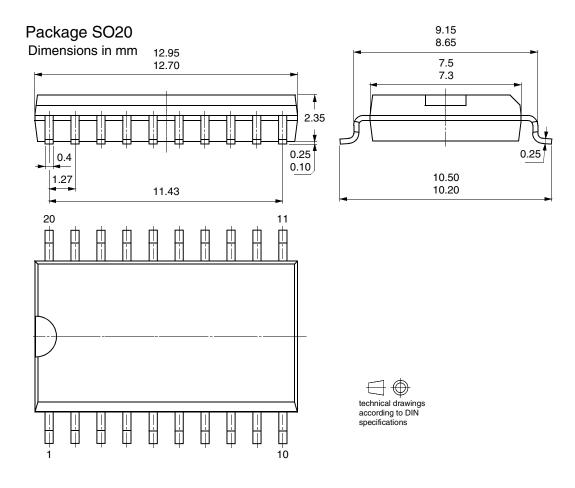
18. Electrical Characteristics (continued) All parameters refer to GND, $T_{amb} = -40^{\circ}$ C to $+105^{\circ}$ C, $V_{S} = 4.5$ V to 5.5V, $f_{0} = 868.3$ MHz and $f_{0} = 915$ MHz, unless otherwise specified. (For typical values: $V_{S} = 5$ V, $T_{amb} = 25^{\circ}$ C)

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Digital Ports				•		
Data output						
 Saturation voltage Low 	$I_{ol} \leq 12 \text{ mA}$	V _{ol}		0.35	0.8	V
	$I_{ol} = 2 \text{ mA}$	V _{ol}		0.08	0.3	V
 max voltage at pin DATA 		V _{oh}			20	V
 quiescent current 	$V_{oh} = 20V$	l _{qu}			20	μA
 short-circuit current 	$V_{ol} = 0.8V$ to 20V	I _{ol_lim}	13	30	45	mA
- ambient temp. in case of	$V_{oh} = 0V$ to 20V	t _{amb_sc}			85	°C
permanent short-circuit						
Data input						
- Input voltage Low		V _{II}			$0.35\timesV_S$	V
- Input voltage High		V _{ich}	$0.65 \times V_S$			V
DATA_CLK output						
 Saturation voltage Low 	IDATA_CLK = 1mA	V _{ol}		0.1	0.4	V
 Saturation voltage High 	$IDATA_CLK = -1mA$	V_{oh}	$V_{S} - 0.4V$	V _S -0.15V		V
IC_ACTIVE output						
- Saturation voltage Low	IIC_ACTIVE = 1 mA	V _{ol}		0.1	0.4	V
- Saturation voltage High	$IIC_ACTIVE = -1 mA$	V _{oh}	V_{S} – 0.4 V	$V_{S} - 0.15 V$		V
POLLING/_ON input						
- Low level input voltage	Receiving mode	V _{II}			$0.2 \times V_{S}$	V
- High level input voltage	Polling mode	V _{lh}	$0.8 \times V_S$		0	V
TEST 4 pin	Testimust must show the second state					
- High level input voltage	Test input must always be set to High	V_{lh}	$0.8 \times V_S$			V
TEST 1 pin						
- Low level input voltage	Test input must always be set to Low	V _{II}			$0.2 \times V_S$	V

19. Ordering Information

Extended Type Number	Package	Remarks
ATA5760N-TGSY	SO20	Tube, for 868 MHz ISM band, Pb-free, $B_{IF} = 600 \text{ kHz}$
ATA5760N-TGQY	SO20	Taped and reeled, for 868 MHz ISM band, Pb-free, $B_{\rm IF}$ = 600 kHz
ATA5761N-TGSY	SO20	Tube, for 915 MHz ISM band, Pb-free, B _{IF} = 600 kHz
ATA5761N-TGQY	SO20	Taped and reeled, for 915 MHz ISM band, Pb-free, $B_{\rm IF}$ = 600 kHz
ATA5760N3-TGQY	SO20	Taped and reeled, for 868 MHz ISM band, Pb-free, $B_{\rm IF}$ = 300 kHz

20. Package Information







21. Revision History

Please note that the following page numbers referred to in this section refer to the specific revision mentioned, not to this document.

Revision No.	History
	Put datasheet in the newest template
4896D-RKE-08/08	 Page 37: Section 18 "Electrical Characteristics" changed
	Page 4: first paragraph changed
	Page 5: text changed
	Page 4.1 IF Filter: text changed
4896C-RKE-04/06	Page 10: text changed
	 Page 30: figures 14-1 and 14-2 changed
	Page 31: El.Char. Table: heading row changed
	Page 35-36: Test condition values changed
	Page 1: PB-free logo deleted
	Page 1: Features changed
	 Page 4: RF Front End - text changed
	Page 5: IF Filter - text changed
4896B-RKE-02/06	 Page 7: Receiving Characteristics - text changed
	Page 7: Fig.5-1 - Title text changed
	Page 8: Fig.5-2 - Title text changed
	 Pages 33 to 37: some lines changed
	 Page 38: Ordering Information table changed



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